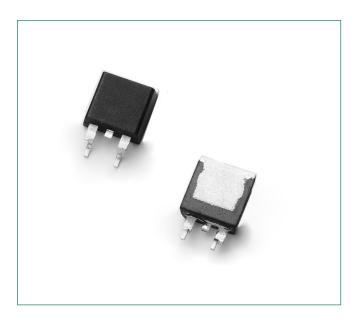


MCR12DCM, MCR12DCN





Description

This thyristor is designed primarily for half-wave ac control applications, such as motor controls, heating controls, and power supplies; or wherever half-wave, silicon gatecontrolled devices are needed.

Features

- Small Size
- Passivated Die for Reliability and Uniformity
- Low Level Triggering and Holding Characteristics
- UL Recognized compound meets flammability rating V-0.
- ESD Ratings: Human Body Model, 3B > 8000 V Machine Model, C > 400 V
- Pb-Free Packages are Available

Pin Out



Functional Diagram



Additional Information







Resources



Maximum Ratings (T _J = 25°C unless otherwise noted)						
Rating		Symbol	Value	Unit		
Peak Repetitive Off-State Voltage (Note 1)	MCR12DCM	V _{DRM}	600	V		
(- 40 to 110°C, Sine Wave, 50 to 60 Hz, Gate Open)	MCR12DCN	V_{RRM}	800	V		
On-State RMS Current (180° Conduction Angles; T _c = 90°C)		I _{T (RMS)}	12	А		
Average On–State Current (180° Conduction Angles; T _c = 90°C)				I _{T(AV)}	7.8	А
Peak Non-Repetitive Surge Current (1/2 Cycle, Sine Wave 60 Hz, T _J = 125°C)		I _{TSM}	100	А		
Circuit Fusing Consideration (t = 8.3 ms)		l²t	41	A²sec		
Forward Peak Gate Power (Pulse Width ≤ 10 µsec,T _C = 90°C)		P _{GM}	5.0	W		
Forward Average Gate Power (t = 8.3 msec , T _c = 90° C)		P _{GM (AV)}	0.5	W		
Forward Peak Gate Current (Pulse Width $\leq 1.0 \mu sec$, $T_c = 90^{\circ}C$)		I _{GM}	2.0	А		
Operating Junction Temperature Range		T _J	-40 to 125	°C		
Storage Temperature Range		T _{stg}	-40 to 150	°C		

Maximum ratings are those values beyond which component damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, component functional operation is not implied, damage may occur and reliability may be affected.

1. V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

Thermal Characteristics

Rating	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	Re _{JC}	2.2	
Thermal Resistance, Junction-to-Ambient	R _{e_{JA}}	88	°C/W
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta_{JA}}$	80	
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	T _L	260	°C

Electrical Characteristics - OFF $(T_J = 25^{\circ}\text{C unless otherwise noted})$

Characteristic		Symbol	Min	Тур	Max	Unit
Peak Repetitive Forward or Reverse Blocking Current ($V_{AK} = Rated V_{DRM}$	T _J = 25°C	I _{DRM}	-	-	0.01	m ^
or V _{RRM} Gate Open)	T _J = 125°C	IRRM	-	-	5.0	mA

Electrical Characteristics - ON (T, = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic		Symbol	Min	Тур	Max	Unit
Peak Forward On–State Voltage (Note 2) (I _{TM} = 16 A)		V _{TM}	_	1.3	1.9	V
Gate Trigger Current (Continuous dc)	T _J = 25°C	1	2.0	7.0	20	mA
$(V_D = 12 \text{ V}; R_L = 100 \Omega)$	$T_J = -40$ °C	I _{GT}	_	_	40	mA
Gate Trigger Voltage (Continuous dc)	T _J = 25°C	V _{GT}	0.5	0.65	1.0	V
$(V_D = 12 \text{ V}, R_L = 100 \Omega)$	T _J = -40°C		_	_	2.5	
Gate Non-Trigger Voltage $(V_D = 12 \text{ V}, R_L = 100 \Omega)$	T _J = 125°C	V _{GD}	0.2	_	_	V
Holding Current	T _J = 25°C		4.0	22	40	A
$(V_D = 12 \text{ V, Gate Open, Initiating Current} = 200 \text{ mA})$	T _J = -40°C	IH	_	_	80	mA
Latch Current $(V_D = 12 \text{ V, I}_G = 20 \mu\text{A, T}_J = 25^{\circ}\text{C})$ $(V_D = 12 \text{ V, I}_G = 40 \mu\text{A, T}_J = -40^{\circ}\text{C})$		I _L -	4.0	22	40	mA
			-	_	80	



Dynamic Characteristics Characteristic **Symbol** Min Тур Max Unit Critical Rate of Rise of Off-State Voltage dv/dt 50 200 V/µs $(V_D = Rated V_{DRM} Exponential Waveform, Gate Open, T_i = 125°C)$

- 2. These ratings are applicable when surface mounted on the minimum pad sizes recommended.
- 3. 1/8* from case for 10 seconds.
 4. Pulse Test: Pulse Width ≤ 2.0 msec, Duty Cycle ≤ 2%.

Voltage Current Characteristic of SCR

Symbol	Parameter	
V_{DRM}	Peak Repetitive Forward Off State Voltage	
I _{DRM}	Peak Forward Blocking Current	
V _{RRM}	Peak Repetitive Reverse Off State Voltage	
IRRM	Peak Reverse Blocking Current	
V _{TM}	Maximum On State Voltage	
I _H	Holding Current	

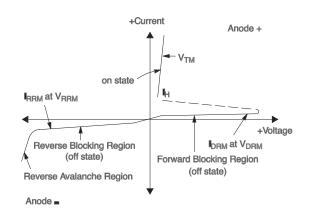


Figure 1. Average RMS Current Derating

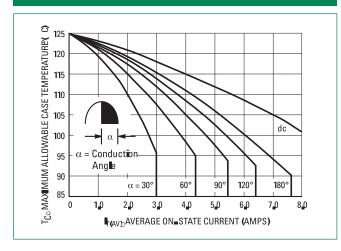


Figure 2. On-State Power Dissipation

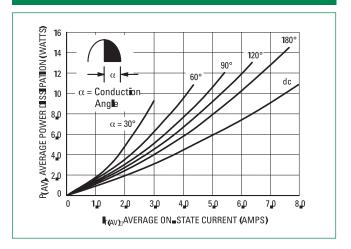




Figure 3. On-State Characteristics

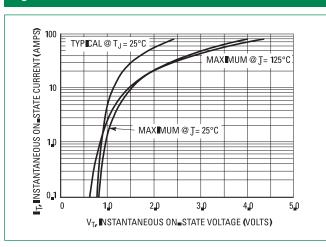


Figure 4. Transient Thermal Response

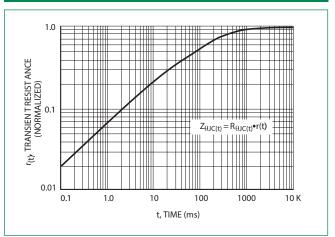


Figure 5. Typical Gate Trigger Current vs Junction Temperature

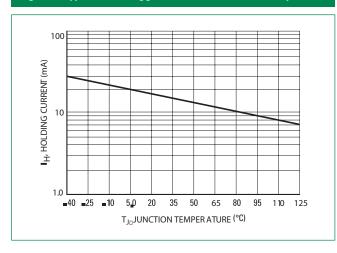


Figure 6. Typical Gate Trigger Voltage vs Junction Temperature

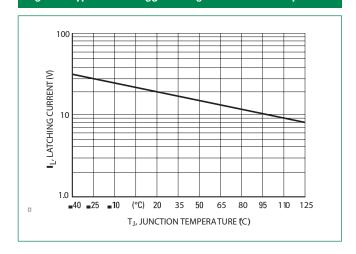


Figure 7. Typical Holding Current vs Junction Temperature

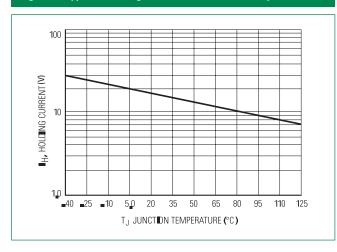
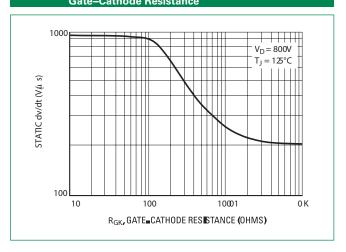
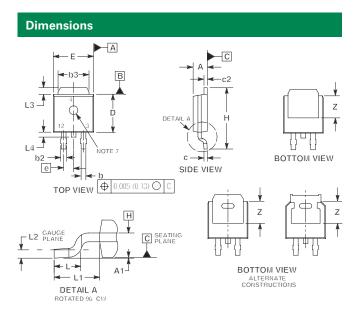


Figure 9. Exponential Static dv/dt vs Gate-Cathode Resistance





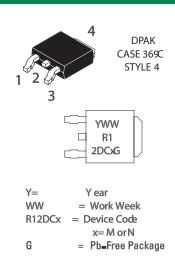


Dim	Inc	hes	Millin	neters	
Dim	Min	Min Max		Max	
А	0.087	0.094	2.20	2.40	
A1	0.000	0.005	0.00	0.12	
b	0.022	0.030	0.55	0.75	
b2	0.026	0.033	0.65	0.85	
b3	0.209	0.217	5.30	5.50	
С	0.019	0.023	0.49	0.59	
c2	0.019	0.023	0.49	0.59	
D	0.213	0.224	5.40	5.70	
Е	0.252	0.260	6.40	6.60	
е	0.0	91	2.30		
Н	0.374	0.406	9.50	10.30	
L	0.058	0.070	1.47	1.78	
L1	0.1	0.114		90	
L2	0.019	0.023	0.49	0.59	
L3	0.053	0.065	1.35	1.65	
L4	0.028	0.039	0.70	1.00	
Z	0.154	-	3.90	-	

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

2. CONTROLLING DIMENSION: INCH.

Part Marking System



Pin Assignment			
1	Cathode		
2	Anode		
3	Gate		
4	Anode		

Ordering Information

Device	Package	Shipping
MCR12DCMT4	DPAK	
MCR12DCMT4G	DPAK (Pb-Free)	2500 /
MCR12DCNT4	TO-220AB	Tape & Reel
MCR12DCNT4G	DPAK (Pb-Free)	

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TN1610H-6I T1700N16H75VTXPSA1 T1400N16H75VTXPSA1 T2600N16TOFVTXPSA1 T1900N16TOFVTXPSA1 VS-ST780C06L0L
NTE5569 2N6403TG 2n6403TG BT148W-600R,115 BT169D-L,116